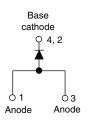
**Vishay Semiconductors** 

FREE

# High Performance Schottky Rectifier, 5.5 A



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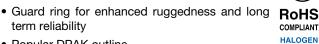


DPAK (TO-252AA)

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	5.5 A			
V <sub>R</sub>	30 V			
V <sub>F</sub> at I <sub>F</sub>	See Electrical table			
I <sub>RM</sub>	58 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	10 mJ			
Package	DPAK (TO-252AA)			
Circuit configuration	Single			

### **FEATURES**

Low forward voltage drop



- Popular DPAK outline
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## DESCRIPTION

The VS-50WQ03FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES U			
I <sub>F(AV)</sub>	Rectangular waveform	5.5	A		
V <sub>RRM</sub>		30	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	320	A		
V <sub>F</sub>	5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.35	V		
TJ	Range	-40 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-50WQ03FNHM3	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	30	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	30	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 136 °C	, rectangular waveform	5.5	А
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	320	A
non-repetitive surge current See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated $V_{RRM}$ applied	130	~
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 5 \text{ mH}$ 10		10	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 2.0		А	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		5 A	T 05 %C	0.46	V
Maximum forward voltage drop	V (1)	10 A	$T_J = 25 \ ^{\circ}C$	0.53	
See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	5 A	- T <sub>J</sub> = 125 °C	0.35	
		10 A		0.46	
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = rated $V_{\rm B}$	3	mA
See fig. 2	IRM \	T <sub>J</sub> = 125 °C	$v_{\rm R} = rateu v_{\rm R}$	58	ША
Threshold voltage	V <sub>F(TO)</sub>	$T_{\rm J} = T_{\rm J}$ maximum $0.19$ 22.22 r		0.19	V
Forward slope resistance	r <sub>t</sub>			mΩ	
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C 590		pF	
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body 5.0 nH		nH	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	3.0	°C/W
Approximate weight			0.3	g
Approximate weight			0.01	oz.
Marking device		Case style DPAK (TO-252AA)	50WQ0	D3FNH

## Note

<sup>(1)</sup>  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink



# VS-50WQ03FNHM3

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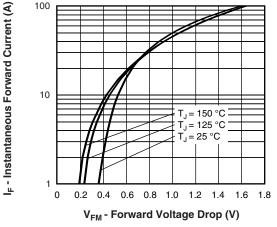


Fig. 1 - Maximum Forward Voltage Drop Characteristics

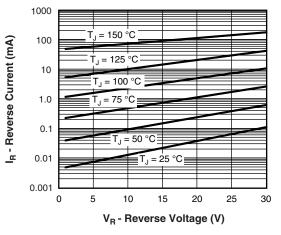


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

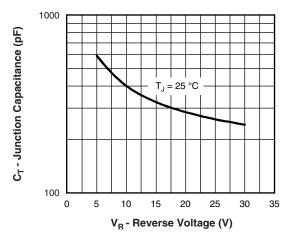
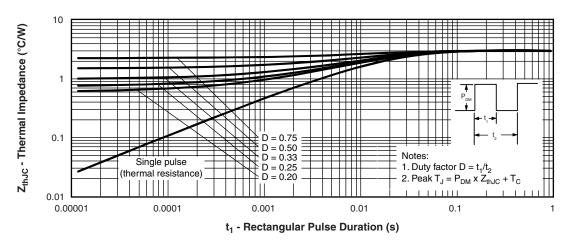
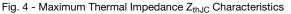


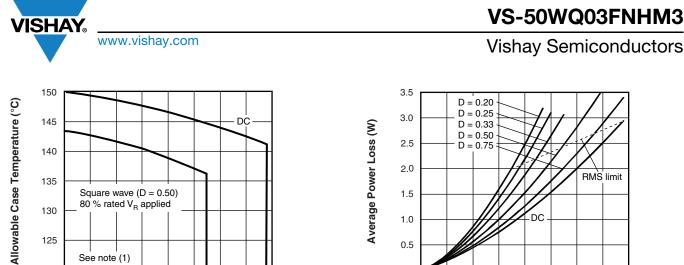
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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 3
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4 I<sub>F(AV)</sub> - Average Forward Current (A)

5 6 7 8

See note (1)

2 3

120

0 1

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

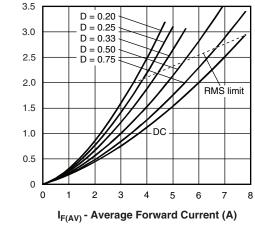


Fig. 6 - Forward Power Loss Characteristics

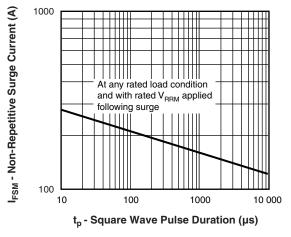


Fig. 7 - Maximum Non-Repetitive Surge Current

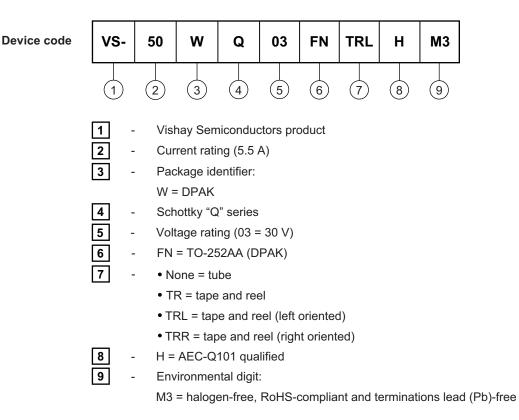
### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{I} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-50WQ03FNHM3	75	3000	Antistatic plastic tube		
VS-50WQ03FNTRHM3	2000	2000	13" diameter reel		
VS-50WQ03FNTRLHM3	3000	3000	13" diameter reel		
VS-50WQ03FNTRRHM3	3000	3000	13" diameter reel		

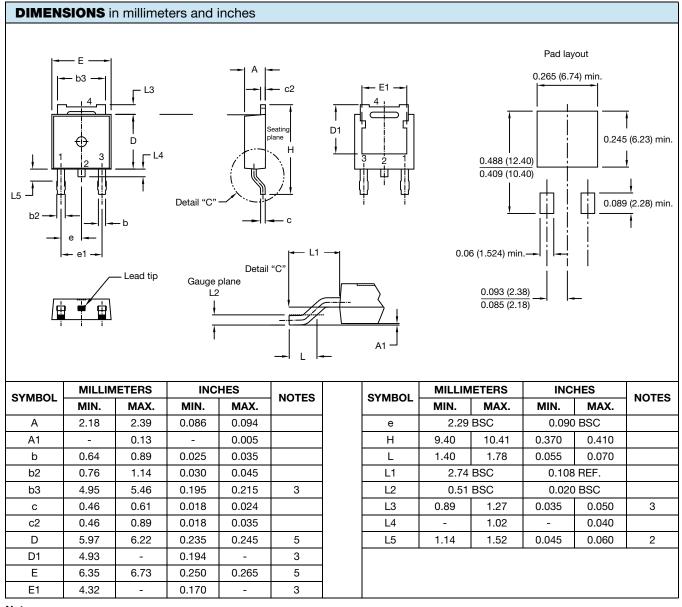
LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?95519</u>			
Part marking information	www.vishay.com/doc?95518		
Packaging information	www.vishay.com/doc?95033		

## **Outline Dimensions**



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# DPAK (TO-252AA)



#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(5)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA, except for D1 dimension



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1